



PDS4150

4A HIGH VOLTAGE SCHOTTKY BARRIER RECTIFIER

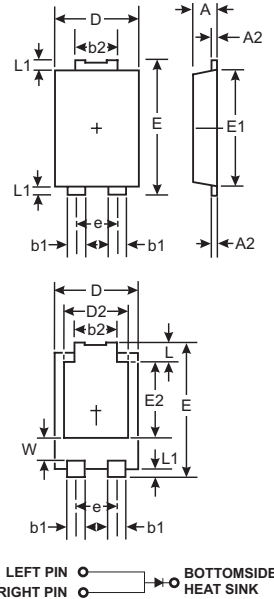
PowerDI™5

Features

- Guard Ring Die Construction for Transient Protection
- Low Forward Voltage Drop
- Very Low Leakage Current
- High Maximum Junction Temperature Capability
- Highly Stable Oxide Passivated Junction
- High Forward Surge Current Capability
- **Lead Free Finish, RoHS Compliant (Note 1)**
- **"Green" Molding Compound (No Br, Sb)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

- Case: PowerDI™5
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish – Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 **(e3)**
- Polarity: See Diagram
- Ordering Information (See Page 3)
- Marking: Type Number (See Page 3)
- Weight: 0.096 grams (approximate)



PowerDI™5		
Dim	Min	Max
A	1.05	1.15
A2	0.33	0.43
b1	0.80	0.99
b2	1.70	1.88
D	3.90	4.05
D2	3.05 NOM	
E	6.40	6.60
e	1.84 NOM	
E1	5.30	5.45
E2	3.55 NOM	
L	0.75	0.95
L1	0.50	0.65
W	1.20	1.50
All Dimensions in mm		

Maximum Ratings @ T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	150	V
RMS Reverse Voltage	V _{R(RMS)}	106	V
Average Rectified Output Current (See also figure 4)	I _O	4	A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave Superimposed on Rated Load	I _{FSM}	180	A
Operating Temperature Range	T _j	-65 to +175	°C
Storage Temperature Range	T _{STG}	-65 to +175	°C

Thermal Characteristics @ T_A = 25°C unless otherwise specified

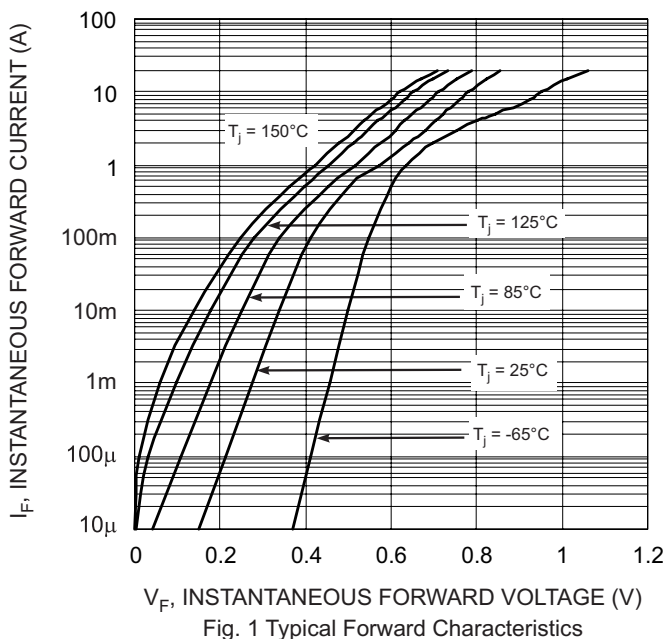
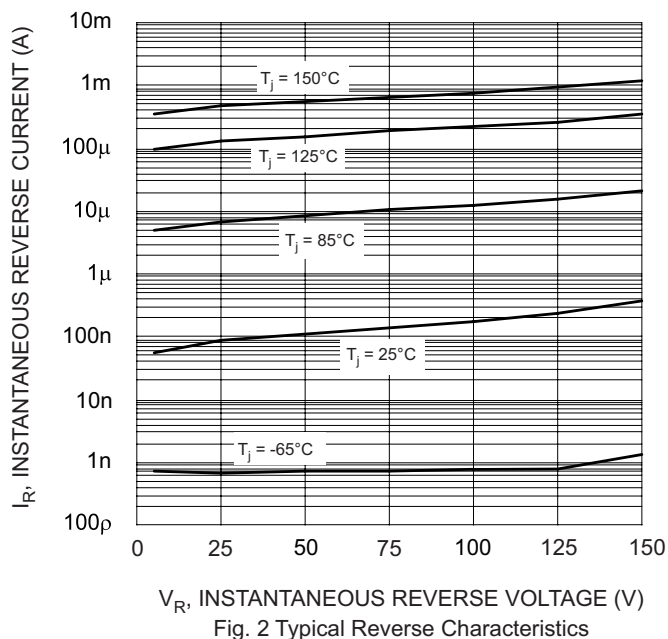
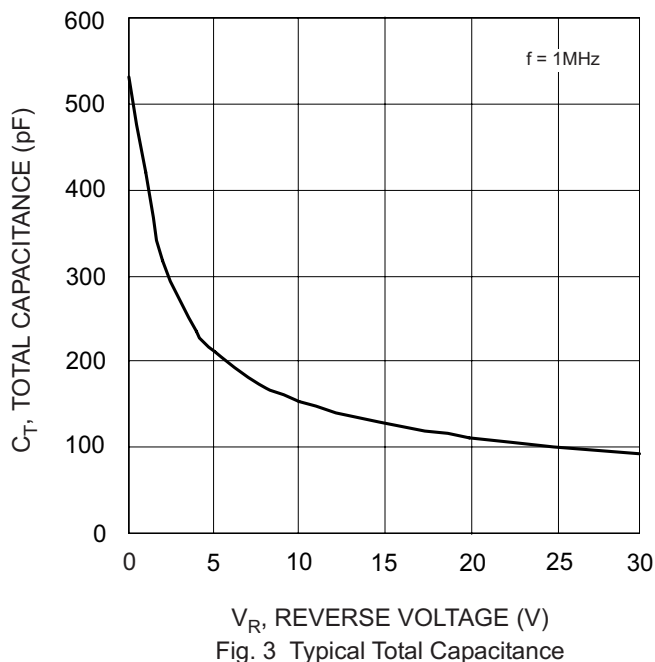
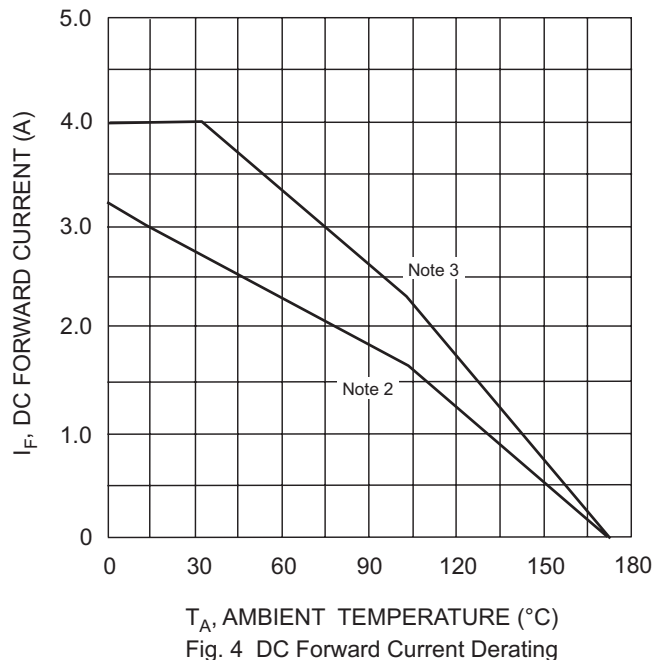
Characteristic	Symbol	Typ	Max	Unit
Thermal Resistance Junction to Soldering Point	R _{θJS}	—	2.0	°C/W
Thermal Resistance Junction to Ambient Air (Note 2)	R _{θJA}	90	—	°C/W
Thermal Resistance Junction to Ambient Air (Note 3)	R _{θJA}	60	—	°C/W
Thermal Resistance Junction to Ambient Air (Note 4)	R _{θJA}	40	—	°C/W

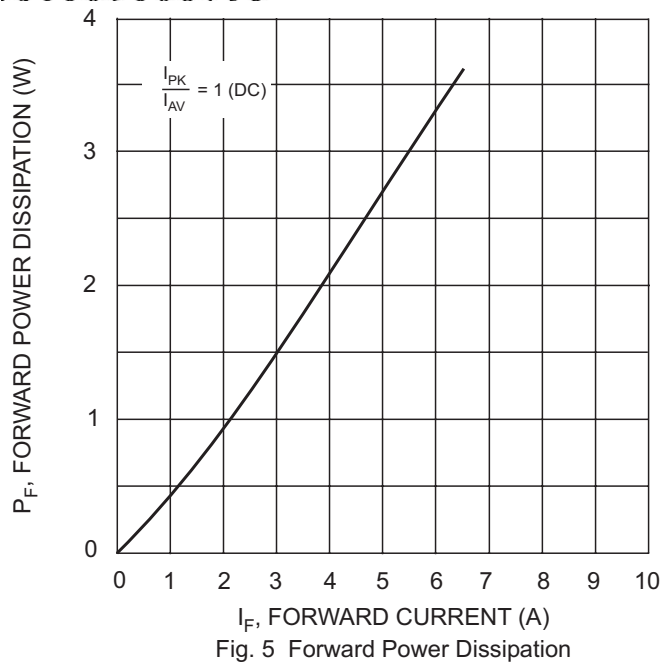
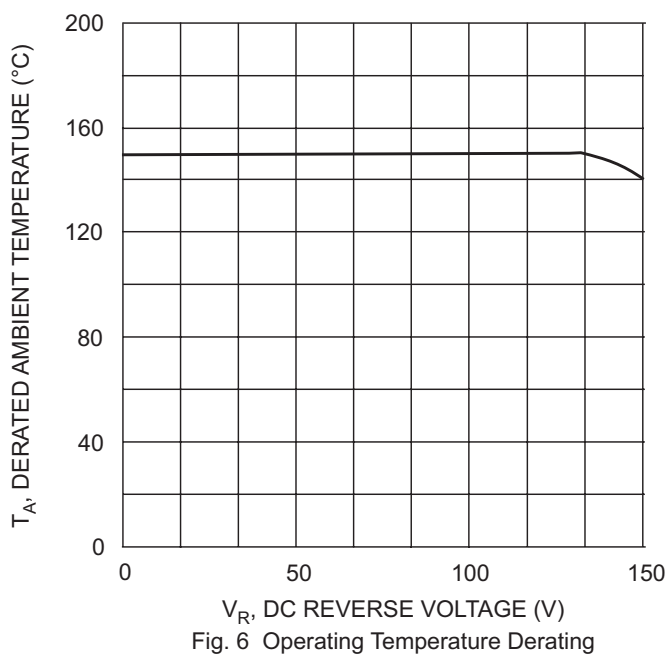
- Notes:
1. RoHS revision 13.2.2003. Glass and High Temperature Solder Exemptions Applied, see *EU Directive Annex Notes 5 and 7*.
 2. FR-4 PCB, 2 oz. Copper, minimum recommended pad layout per <http://www.diodes.com/datasheets/ap02001.pdf>.
 3. Polyimide PCB, 2 oz. Copper, minimum recommended pad layout per <http://www.diodes.com/datasheets/ap02001.pdf>.
 4. Polyimide PCB, 2 oz. Copper. Cathode pad dimensions 9.4 mm x 7.2 mm. Anode pad dimensions 2.7 mm x 1.6 mm.

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 5)	$V_{(BR)R}$	150	—	—	V	$I_R = 10\mu\text{A}$
Forward Voltage	V_F	—	0.71 0.57 — 0.63	0.76 0.64 0.81 0.70	V	$I_F = 4\text{A}$, $T_S = 25^\circ\text{C}$ $I_F = 4\text{A}$, $T_S = 125^\circ\text{C}$ $I_F = 8\text{A}$, $T_S = 25^\circ\text{C}$ $I_F = 8\text{A}$, $T_S = 125^\circ\text{C}$
Reverse Leakage Current (Note 5)	I_R	—	0.3 0.4	10 4.5	μA mA	$T_S = 25^\circ\text{C}$, $V_R = 150\text{V}$ $T_S = 125^\circ\text{C}$, $V_R = 150\text{V}$

Notes: 5. Short duration test pulse used to minimize self-heating effect.



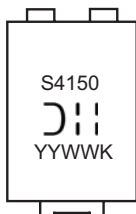


Ordering Information (Note 6)

Device	Packaging	Shipping
PDS4150-13	PowerDI™5	5000/Tape & Reel

Notes: 6. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



S4150 = Product type marking code
 Diodes logo = Manufacturers' code marking
 YYWW = Date code marking
 YY = Last two digits of year ex: 05 for 2005
 WW = Week code 01 to 52
 K = Factory Designator